



PNP PRE-BIASED TRANSISTOR

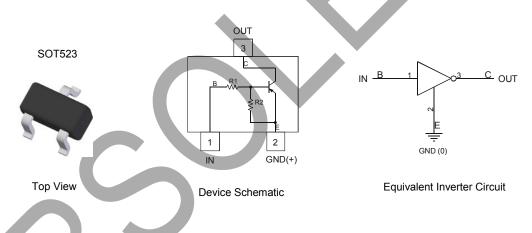
Features

- Epitaxial Planar Die Construction
- Complementary NPN Types Available (DDTC)
- Built-In Biasing Resistors
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen- and Antimony-Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

Mechanical Data

- Case: SOT-523
- Case Material: Molded Plastic, "Green" Molding Compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.002 grams (approximate)

Part Number	R1 (NOM)	R2 (NOM)
DDTA122LE	0.2kΩ	10kΩ
DDTA142JE	0.47kΩ	10kΩ
DDTA122TE	0.22kΩ	OPEN
DDTA142TE	0.47kΩ	OPEN



Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DDTA122LE-7-F	Standard	P81	7	8	3000
DDTA142JE-7-F	Standard	P82	7	8	3000
DDTA122TE-7-F	Standard	P83	7	8	3000
DDTA142TE-7-F	Standard	P84	7	8	3000

Notes:

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



2031

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Nov

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2032

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Dec

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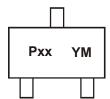
Marking Information

2021

Т

Jan

1



2024

L

Apr

4

Pxx = Product Type Marking Code (See Ordering Information) YM = Date Code Marking Y or Y = Year (ex: I = 2021) M = Month (ex: 9 = September)

2028

Ρ

Aug

8

2029

R

Sep

9

2030

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Oct

0

2027

0

Jul

7

2026

Ν

Jun

6

Date Code Key	y
Year	
Code	
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2022

J

Feb

2

2023

Κ

Mar

3

Characteristic		Symbol	Value	Unit
Supply Voltage, (2) to (3)		Vcc	-50	V
Input Voltage, (1) to (2)	DDTA122LE DDTA142JE	V _{IN}	+5 to -6 +5 to -6	V
Input Voltage, (2) to (1)	DDTA122TE DDTA142TE	V _{EBO (MAX)}	-5	V
Output Current	All	Ι _C	-100	mA

2025

Μ

May

5

Thermal Characteristics (@ T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	150	mW
Thermal Resistance, Junction to Ambient Air (Note 5)	R _{0JA}	625	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Notes:

5. For a device surface mounted on 15mm x 15mm x 0.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; device measured when operating in steady state condition.



Electrical Characteristics (@ T_A = +25°C, unless otherwise specified.) R1, R2 Types

Characteristic	Symbol	Min	Тур	Мах	Unit	Test Condition	
Input Voltage	DDTA122LE DDTA142JE	V _{l(off)}	-0.3 -0.3	_	_	V	V _{CC} = -5V, I _O = -100µA
	DDTA122LE DDTA142JE	V _{l(on)}	_	_	-2.0 -2.0	V	V _O = -0.3V, I _O = -20mA V _O = -0.3V, I _O = -20mA
Output Voltage		V _{O(on)}	_	_	-0.3V	V	I _O /I _I = -5mA/-0.25mA
Input Current	DDTA122LE DDTA142JE	II.	_	_	-28 -13	mA	V ₁ = -5V
Output Current		I _{O(off)}	_	_	-0.5	μA	V _{CC} = -50V, V _I = 0V
DC Current Gain DDTA122LE DDTA142JE		Gı	56 56	_	_		V _O = -5V, I _O = -10mA
Transition frequency		f⊤	_	200		MHz	V _{CE} = -10V, I _E = -5mA, f = 100MHz

Electrical Characteristics @ T_A = 25°C unless otherwise specified R1-Only Types

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage		ВV _{CBO}	-50		_	V	I _C = -50μA
Collector-Emitter Breakdown Voltag	е	BV _{CEO}	-40	_		V	I _C = -1mA
Emitter-Base Breakdown Voltage	DDTA122TE DDTA142TE	BV _{EBO}	-5	_	_	V	I _E = -50μA I _E = -50μA
Collector Cutoff Current		I _{СВО}	_		-0.5	μA	V _{CB} = -50V
Emitter Cutoff Current	DDTA122TE DDTA142TE	I _{EBO}			-0.5 -0.5	μA	V _{EB} = -4V
Collector-Emitter Saturation Voltage		V _{CE(sat)}	_		-0.3	V	I _C = -5mA, I _B = -0.25mA
DC Current Gain	DDTA122TE DDTA142TE	h _{FE}	100 100	250 250	600 600		I _C = -1mA, V _{CE} = -5V
Transition frequency		f⊤		200		MHz	V _{CE} = -10V, I _E = 5mA, f = 100MHz



250

200

150

100

50

0 └ -50 R_{0JA} = 625 °C/W

0

50

T_A, AMBIENT TEMPERATURE (°C) **Derating Curve**

P_d, POWER DISSIPATION (mW)

Typical Electrical Characteristics (@ T_A = +25°C unless otherwise specified.)

100

150

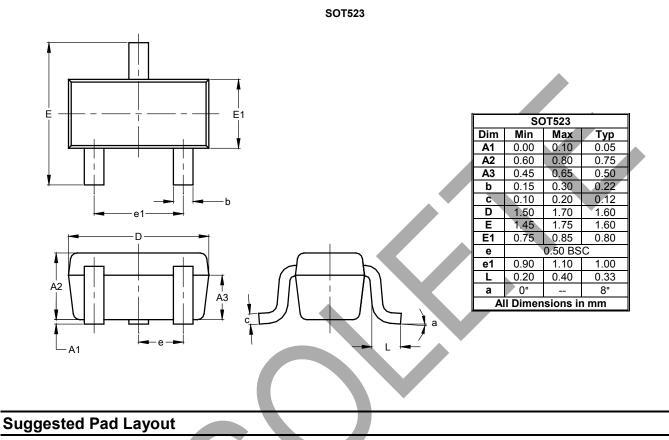




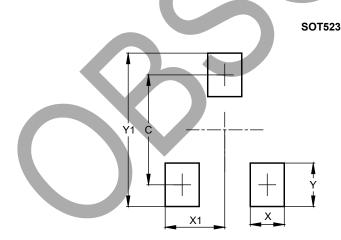


Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



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Dimensions	Value
С	1.29
Х	0.40
X1	0.70
Y	0.51
Y1	1.80



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